EE 330

Homework 5 Solutions

Fall 2020

Solution 1

From L13

$$R(T_2) = R(T_1)[1 + (T_2 - T_1)\frac{TCR}{10^6}]$$

So $R(300) = R(273)\left[1 + (27)\frac{1100}{10^6}\right] = 1029.7\Omega$

Solution 2

300 and 320 $R(T) = 5T + 1000 \Rightarrow R(25) = 1125$ and R(47) = 1235 From L13

$$1235 = 1125 \left[1 + (22) \frac{TCR}{10^6} \right] \Rightarrow TCR = 4444ppm/^{\circ}C$$

Solution 3

From L13

$$\begin{split} R(T_2) &= R(T_1)[1 + (T_2 - T_1)\frac{TCR}{10^6}] \\ \text{So } R_1(T_2) + R_2(T_2) &= R_1(T_1)\left[1 + (T_2 - T_1)\frac{TCR_1}{10^6}\right] + R_2(T_1)\left[1 + (T_2 - T_1)\frac{TCR_2}{10^6}\right] \\ &= R_1(T_1) + R_2(T_1) + (T_2 - T_1)\left[R_1(T_1)\frac{TCR_1}{10^6} + R_2(T_1)\frac{TCR_2}{10^6}\right] \\ &= 5*10^3 + (T_2 - T_1)\left[5*10^3\frac{360}{10^6}\right] \\ &= 5*10^3 + 5*10^3(T_2 - T_1)\frac{360}{10^6} = 5*10^3(1 + (T_2 - T_1)\frac{360}{10^6}) \text{ which means the equivalent TCR is } 360\text{ppm/C} \end{split}$$

Solution 4

 $\lambda = 0.3 \mu m$ and the minimum width for poly is 2λ

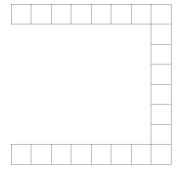
For one square $W=L=2*0.3\mu m=0.6\mu m$

$$A_{\Box} = 0.6 \mu m * 0.6 \mu m = 0.36 \mu m$$

Sheet Resistance =
$$23.5\frac{\Omega}{\Box}$$

We can start by imagining the letter "c" made from these squares. Each side should have n number of squares to add up so that the total resistance is 500Ω .

If we take $\frac{500}{23.5} = 21.3$ squares. If we divide by 3 to get how many we will have on each side, we roughly get 7. Since the corners will amount to less, I will check for a square where each side is 8 instead. So let us implement it and check:



Each of the squares that are not a corner are 23.5Ω and the corners are $0.55*23.5\Omega$.

So total we have:

$$(7+6+7) * 23.5\Omega + 2 * 0.55 * 23.5\Omega = 495.85\Omega$$

Solution 5

I will use M1, M2 and M3 layers.

From M1 to M2 the capacitance is $31aF/\mu m^2$

From M2 to M3 the capacitance is $35aF/\mu m^2$

If we layer all 3 layers on top of each other, we make 2 capacitors in series.

$$A_{capM1M2} = \frac{A}{31aF/\mu m^2}$$

$$A_{capM2M3} = \frac{B}{35aF/\mu m^2}$$

where A+B=100fF. Since I am shooting for the areas to be the same

$$\frac{B}{35aF/\mu m^2} = \frac{A}{31aF/\mu m^2} \Rightarrow B = 1.129A$$

$$\frac{1}{A} + \frac{1}{B} = \frac{1}{100fF} \Rightarrow \frac{1.8857}{A} = \frac{1}{100fF} \Rightarrow A = 188.57fF \text{ and } B = 212.9fF$$
So the total $A = \frac{46.97fF}{31aF/\mu m^2} + \frac{53.03fF}{35aF/\mu m^2} = 1515.16 + 1522.85 = 3038\mu m^2$

That means each side will be $55.12\mu m$ and the layers will be stacked on themselves with the one side of the capacitor being on Metal 1 and the other on Metal 3.

Solution 6

Recall that the diode through a pn junction diode can be modeled as $I_D = J_s A(e^{\frac{V_D}{V_T}} - 1)$. Assuming that $V_T \approx 26mV$ at room temperature:

$$I_{D,0.5V} = [10^{-15}][75] \left(e^{\frac{0.5}{0.026}} - 1\right) = 16.9\mu A$$

$$I_{D,0.5V} = [10^{-15}][75] \left(e^{\frac{0.6}{0.026}} - 1\right) = 789\mu A$$

$$16.9\mu A \le I_D \le 789\mu A$$



55.12um